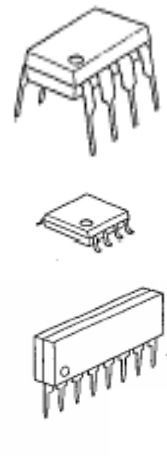
Low Power Dual Operational Amplifier

IL2904

The IL2904 contains two independent high gain operational amplifiers with internal frequency compensation. The two op-amps operate over a wide voltage range from a single power supply. Also use a split power supply. The device has low power supply current drain, regardless of the power supply voltage. The low power drain also makes the IL2904 a good choice for battery operation.

When your project calls for a traditional op-amp function, now you can streamline your design with a simple single power supply. Use ordinary + 5VDC common to practically any digital system or personal computer application, without requiring an extra 15V power supply just to have the interface electronics you need.

The IL2904 is a versatile, rugged workhorse with a thousand-and-one uses, from amplifying signals from a variety of transducers to dc gain blocks, or any op-amp function. The attached pages offer some recipes that will have your project cooking in no time.

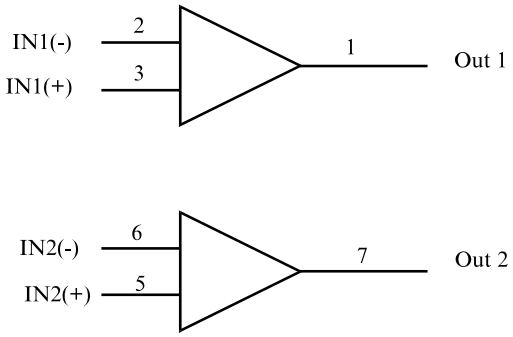


ORDERING INFORMATION

IL2904N Plastic
IL2904D SOIC
IL2904S SIP-8
T_A = -40° to 85° C for all packages.

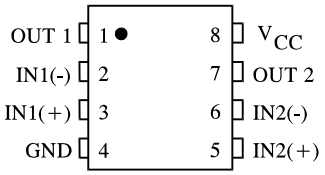
- Internally frequency compensated for unity gain
- Large DC voltage gain: 100dB
- Wide power supply range:
  3V ~ 32V (or ±1.5V ~ ±16V)
- Input common-mode voltage range includes ground
- Large output voltage swing: 0V DC to V_{CC}-1.5V DC
- Power drain suitable for battery operation
- Low input offset voltage and offset current
- Differential input voltage range equal to the power supply voltage
- Possible to exchange the position of Pin9 for Pin1 because of Pin Connection being symmetric(IL2904S only)

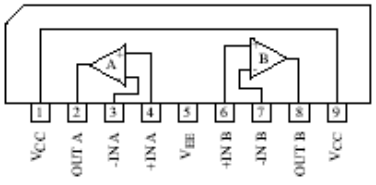
LOGIC DIAGRAM



PIN 4 = GND
PIN 8= V_{CC}

PIN ASSIGNMENT





MAXIMUM RATINGS*

Symbol	Parameter	Value	Unit
V_{CC}	Power Supply Voltages Single Supply Split Supplies	 32 ±16	 V
V_{IDR}	Input Differential Voltage Range (1)	±32	V
V_{ICR}	Input Common Mode Voltage Range	-0.3 to 32	V
I_{SC}	Output Short Circuit Duration	Continuous	
T_J	Junction Temperature Plastic Packages	 150	 °C
Tstg	Storage Temperature Plastic Packages	 -55 to + 125	°C
I_{IN}	Input Current, per pin (2)	50	mA
T_L	Lead Temperature, 1mm from Case for 10 Seconds	260	°C

* Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied.
Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Functional operation should be restricted to the Recommended Operating Conditions.
+ Derating - Plastic DIP: - 10 mW/°C from 65° to 125°C
SOIC Package: : - 7 mW/°C from 65° to 125°C
Notes:
1. Split Power Supplies.
2. V_{IN}< -0.3V. This input current will only exist when voltage at any of the input leads is driven negative.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V_{CC}	DC Supply Voltage	±2.5 or 5.0	±15 or 30	V
T_A	Operating Temperature, All Package Types	-40	+ 85	°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{IN} and V_{OUT} should be constrained to the range GND≤(V_{IN} or V_{OUT})≤V_{CC}.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

DC ELECTRICAL CHARACTERISTICS (T_A= -40 to + 85°C)

Symbol	Parameter	Test Conditions	Guaranteed Limit			Unit
			Min	Typ	Max	
V_{IO}	Maximum Input Offset Voltage	V_O= 1.4V V_{CC}= 5.0-30V;R_S= 0Ω V_{ICM}= 0V to V_{CC}-1.7V			9.0 5.0*	mV
$\Delta V_{IO}/\Delta T$	Input Offset Voltage Drift	R_S= 0Ω, V_{CC}= 30V		7.0		μV/°C
I_{IO}	Maximum Input Offset Current	V_{CC}= 5.0V			150 50*	nA
$\Delta I_{IO}/\Delta T$	Input Offset Current Drift	R_S= 0Ω, V_{CC}= 30V		10		pA/°C
I_{IB}	Maximum Input Bias Current	V_{CC}= 5.0V			500 250*	nA
V_{ICR}	Input Common Mode Voltage Range	V_{CC}= 30V	0		28	V
I_{CC}	Maximum Power Supply Current	R_L= ∞,V_{CC}= 30V,V_0= 0V R_L= ∞,V_{CC}= 5V,V_0= 0V			3 1.2	mA
A_{VOL}	Minimum Large Signal Open-Loop Voltage Gain	V_{CC}= 15V, R_L≥2KΩ	15 25*			V/mV
V_{OH}	Minimum Output High-Level Voltage Swing	V_{CC}= 30V,R_L= 2KΩ V_{CC}= 30V,R_L= 10KΩ	26 27			V
V_{OL}	Maximum Output Low-Level Voltage Swing	V_{CC}= 5V,R_L= 10KΩ			20	mV
CMR	Common Mode Rejection	V_{CC}= 30V, R_S= 10KΩ	65*			dB
PSR	Power Supply Rejection	V_{CC}= 30V	65*			dB
CS	Channel Separation	f= 1KHz to 20KHz,V_{CC}= 30V	-120*			dB
I_{SC}	Maximum Output Short Circuit to GND	V_{CC}= 5.0V			60*	mA
I_{source}	Minimum Source Output Current	V_{IN+}= 1V, V_{IN-}= 0V, V_{CC}= 15V, V_0= 0V	10			mA
I_{sink}	Minimum Output Sink Current	V_{IN+}= 0V, V_{IN-}= 1V, V_{CC}= 15V, V_0= 15V V_{IN+}= 0V, V_{IN-}= 1V, V_{CC}= 15V, V_0= 0.2V	5 10* 12*			mA μA
V_{IDR}	Differential Input Voltage Range	All V_{IN}≥GND or V-Supply (if used)			V_{CC}*	V

*= @25°C

TYPICAL PERFORMANCE CHARACTERISTICS

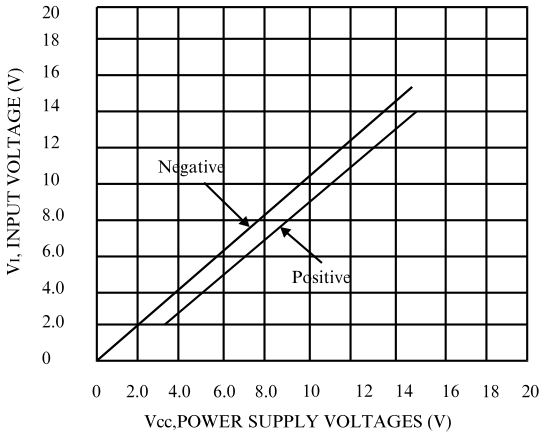


Figure 1. Input Voltage Range

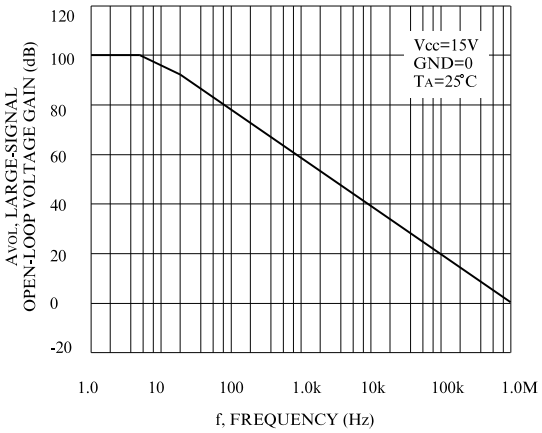


Figure 2. Open-Loop Frequency

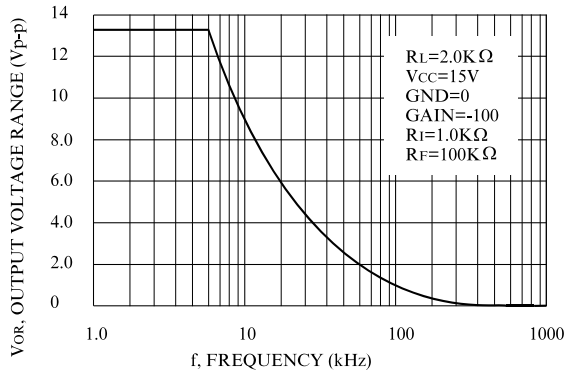


Figure 3. Large-Signal Frequency Response

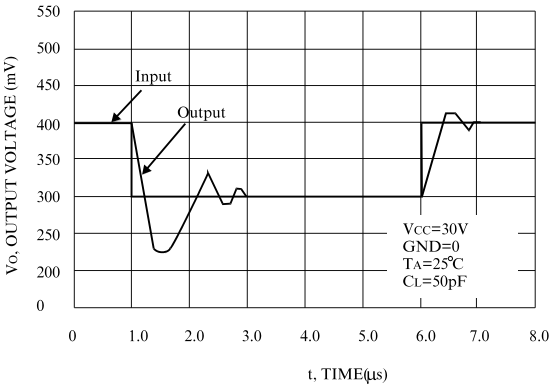


Figure 4. Small-Signal Voltage Follower Pulse Response (Noninverting)

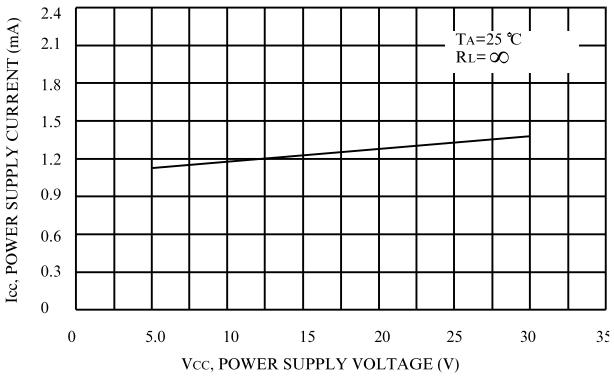


Figure 5. Power Supply Current versus Power Supply Voltage

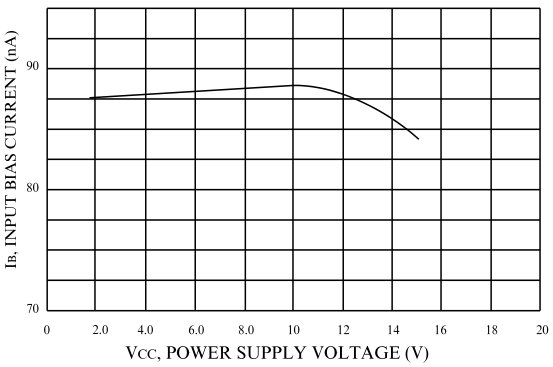
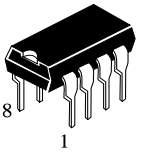
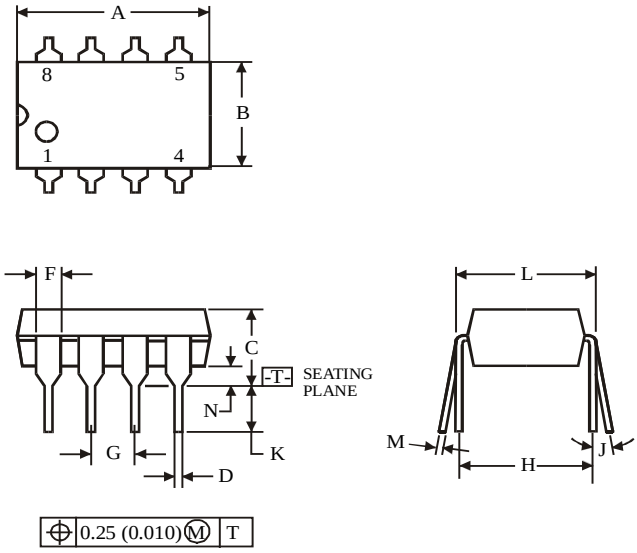


Figure 6. Input Bias Current versus Power Supply Voltage

N SUFFIX PLASTIC DIP
(MS – 001BA)



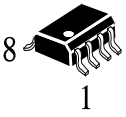


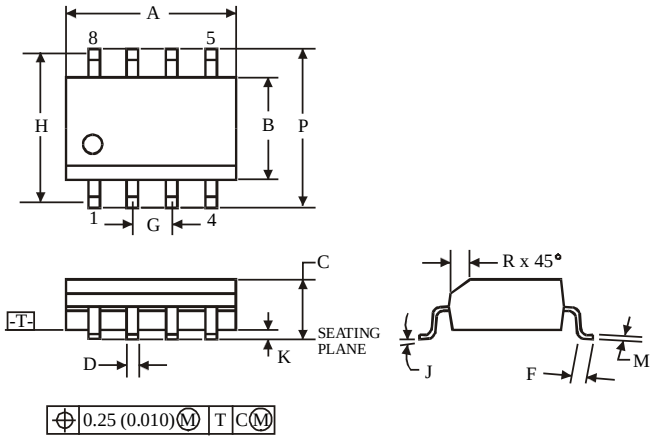
	Dimension, mm	
Symbol	**MIN**	**MAX**
A	8.51	10.16
B	6.1	7.11
C		5.33
D	0.36	0.56
F	1.14	1.78
G	2.54	
H	7.62	
J	0°	10°
K	2.92	3.81
L	7.62	8.26
M	0.2	0.36
N	0.38	

NOTES:

1. Dimensions “A”, “B” do not include mold flash or protrusions.
   Maximum mold flash or protrusions 0.25 mm (0.010) per side.

D SUFFIX SOIC
(MS - 012AA)





	Dimension, mm	
Symbol	**MIN**	**MAX**
A	4.8	5
B	3.8	4
C	1.35	1.75
D	0.33	0.51
F	0.4	1.27
G	1.27	
H	5.72	
J	0°	8°
K	0.1	0.25
M	0.19	0.25
P	5.8	6.2
R	0.25	0.5

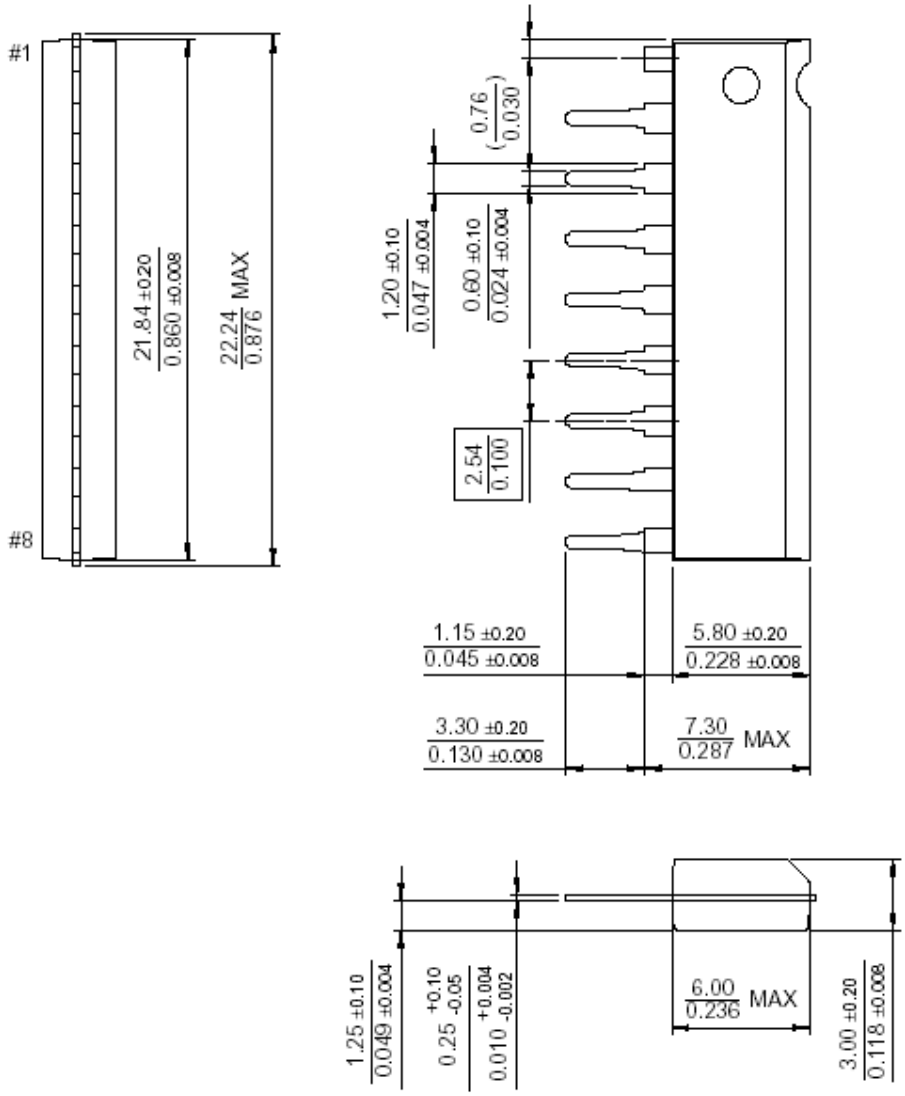
NOTES:

1. Dimensions A and B do not include mold flash or protrusion.
2. Maximum mold flash or protrusion 0.15 mm (0.006) per side
   for A; for B – 0.25 mm (0.010) per side.

Mechanical Dimensions (Continued)

Package

9-SIP



Общество с ограниченной ответственностью «МосЧип» ИНН 7719860671 / КПП 771901001
Адрес: 105318, г.Москва, ул.Щербаковская д.3, офис 1107

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

http://moschip.ru/get-element

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:
moschip.ru
moschip.ru_4
moschip.ru_6
moschip.ru_9